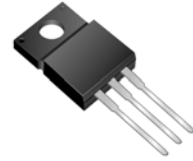


## Features

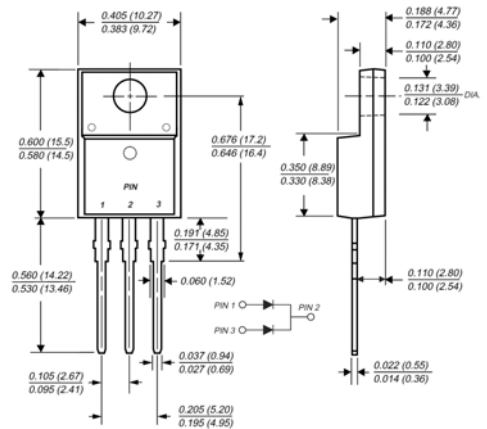
- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-O utilizing Flame Retardant Epoxy Molding Compound.
- ◆ Exceeds environmental standards of MIL-S-19500/228
- ◆ Low power loss, high efficiency
- ◆ Low forward voltage, high current capability
- ◆ High surge capacity
- ◆ Ultra fast recovery times, high voltage



ITO-220AB

## Mechanical Data

- ◆ Case: ITO-220AB full molded plastic package
- ◆ Terminals: Lead solderable per MIL-STD-202, Method 208
- ◆ Polarity: As marked
- ◆ Standard packaging: Any
- ◆ Weight: 0.08 ounces, 2.24 grams



## Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Parameter	Symbol	UF 1600FCT	UF 1601FCT	UF 1602FCT	UF 1603FCT	UF 1604FCT	UF 1606FCT	UF 1608FCT	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	300	400	600	800	Volts
Maximum RMS voltage	$V_{RMS}$	35	70	140	210	280	420	560	Volts
Maximum DC blocking voltage	$V_{DC}$	50	100	200	300	400	600	800	Volts
Maximum average forward rectified current at $T_C=100^\circ\text{C}$	$I_{F(AV)}$	16.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	125.0							Amps
Maximum instantaneous forward voltage at 8.0A	$V_F$	1.0			1.3		1.7		Volts
Maximum DC reverse current at rated DC blocking voltage @ $T_A=25^\circ\text{C}$ @ $T_A=125^\circ\text{C}$	$I_R$	10.0 500							$\mu\text{A}$
Maximum reverse recovery time at $I_S=0.5\text{A}$ , $I_R=1.0\text{A}$ , $I_F=0.25\text{A}$ (Note 1)	$t_{rr}$	50						100	nS
Typical junction capacitance at 4.0V, 1MHz (Note 2)	$C_J$	170.0						130.0	pF
Typical thermal resistance (Note 3)	$R_{\theta JC}$	2.0							$^\circ\text{C/W}$
Operating junction and storage temperature range	$T_{J, T_{STG}}$	-55 to +150							$^\circ\text{C}$

- Notes:**
1. Reverse Recovery Test Conditions:  $I_S=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_F=0.25\text{A}$ .
  2. Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
  3. Thermal resistance from Junction to ambient and from junction to lead 0.375" (9.5mm) P.C.B mounted.

# RATINGS AND CHARACTERISTIC CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

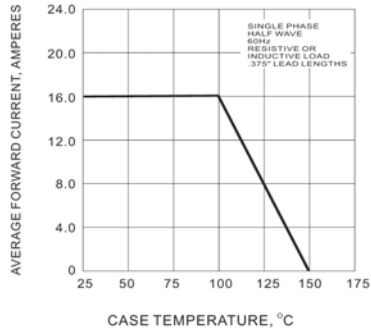


Fig.1 FORWARD CURRENT DERATING CURVE

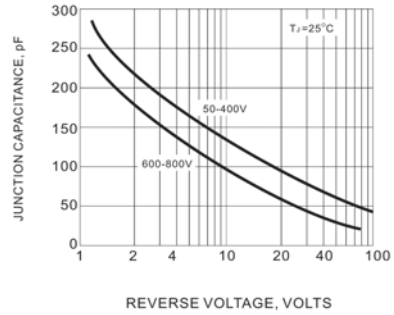


Fig.2 TYPICAL JUNCTION CAPACITANCES

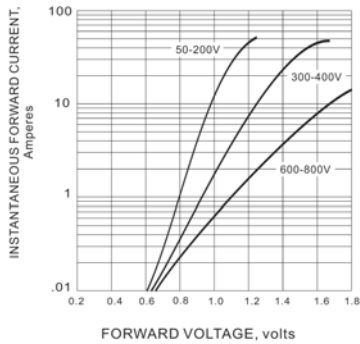


Fig.3 FORWARD CHARACTERISTICS

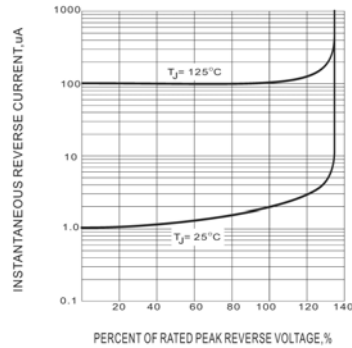


Fig.4 TYPICAL REVERSE CHARACTERISTICS

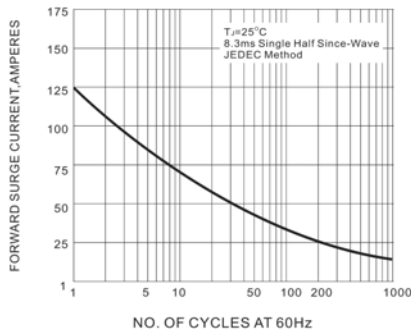


Fig.5 PEAK FORWARD SURGE CURRENT

Web site: <http://www.semiteltech.com>

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